NSN 5962-00-434-3071

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-00-434-3071

view Online at https://aerobasegroup.com/nsn/5962-00-454-3071
Body Length:
Between 1.208 inches and 1.232 inches
Body Width:
Between 0.495 inches and 0.505 inches
Body Height:
0.060 inches
Maximum Power Dissipation Rating:
1.25 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and programmable and programmed and high speed and low power
Inclosure Material:
Ceramic and metal
Inclosure Configuration:
Dual-in-line
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Gold
Voltage Rating And Type Per Characteristic:
0.3 volts power source
Time Rating Per Chacteristic:
100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Precious Material And Location:
Terminal surface gold
Precious Material:
Gold
Test Data Document:

12464-b77t0197 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

NSN 5962-00-434-3071

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

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